

500V N-CHANNEL ENHANCEMENT MODE MOSFET

MAIN CHARACTERISTICS

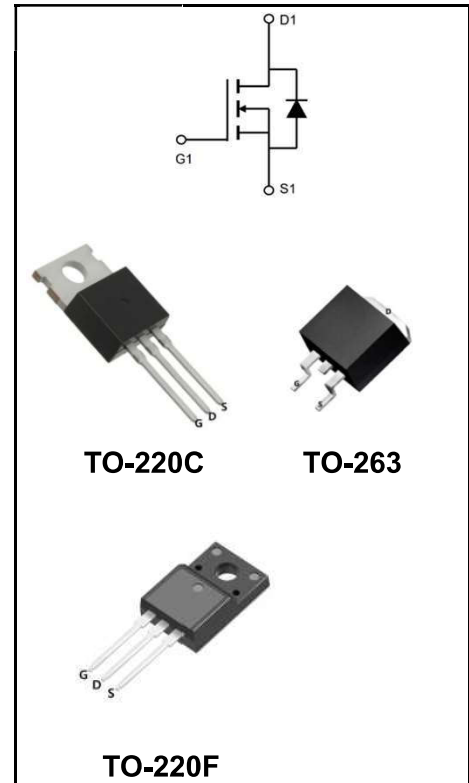
I_D	10A
V_{DSS}	500V
R_{DS(on)-typ(@V_{GS}=10V)}	<0.66Ω (Type:0.45Ω)

Features

- ◆Fast Switching
- ◆Low ON Resistance
- ◆Low Gate Charge
- ◆100% Single Pulse avalanche energy Test
- ◆LeadfreeincomplywithEURoHS2011/65/EUdirectives

Mechanical Data

- ◆Case: Molded plastic
- ◆Mounting Position: Any
- ◆Molded Plastic: UL Flammability Classification Rating 94V-0
- ◆Solder bath temperature275℃maximum,10s per JESD22-106



Product Specification Classification

Part Number	Package	Marking	Pack
YFW10N50BC	TO-220C	YFW 10N50BC XXXXX	1000PCS/Box
YFW10N50BF	TO-220F(0.5mm)	YFW 10N50BF XXXXX	1000PCS/Box
YFW10N50BF	TO-220F(1.3mm)	YFW 10N50BF XXXXX	1000PCS/Box
YFW10N50BS	TO-263	YFW 10N50BS XXXXX	800PCS/Reel
YFW10N50BS-G	TO-263	YFW 10N50BS XXXXX	1000PCS/Box

Maximum Ratings at Tc=25°C unless otherwise specified

Characteristics	Symbols	Value			Units
		220C	220F	263	
Drain-Source Voltage	V_{DS}	500			V
Gate-Source Voltage	V_{GS}	±30			V
Continue Drain Current-Continuous (TC = 25°C)	I_D	10			A
-Continuous (TC = 100°C)		6			
Pulsed Drain Current (Note1)	I_{DM}	40			A
Power Dissipation	P_D	143	48	140	W
-Derate above 25°C		1.14	0.38	1.14	W/°C
Single Pulse Avalanche Energy (Note2)	E_{AS}	650			mJ
Avalanche Current (Note 1)	I_{AR}	10			A
Repetitive Avalanche Energy (Note 1)	E_{AS}	14			mJ
Operating Temperature Range	T_J	150			°C
Storage Temperature Range	T_{STG}	-55 to +150			°C
Thermal Resistance, Junction to Case	R_{θJC}	0.92	2.68	0.92	°C/W
Thermal Resistance, Junction to Ambient	R_{θJA}	62.5	62.5	62.5	°C/W

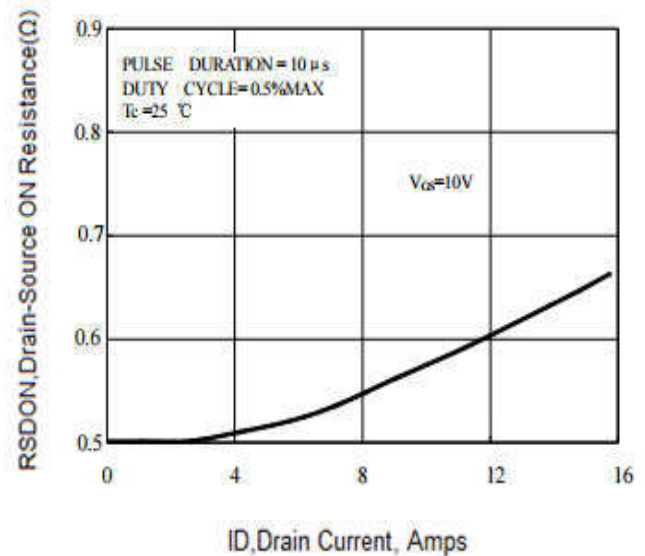
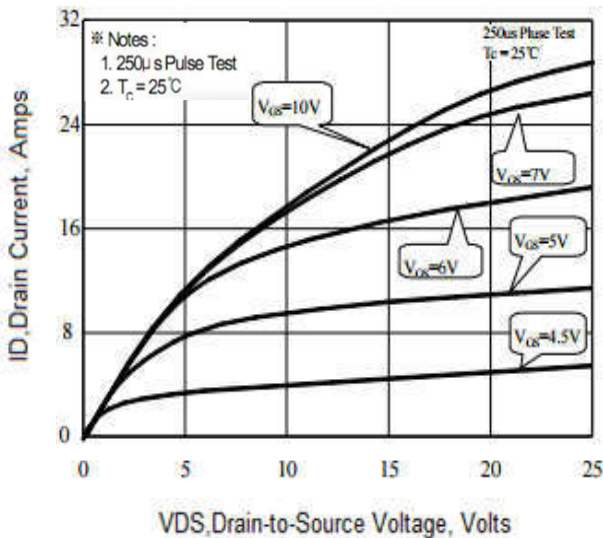
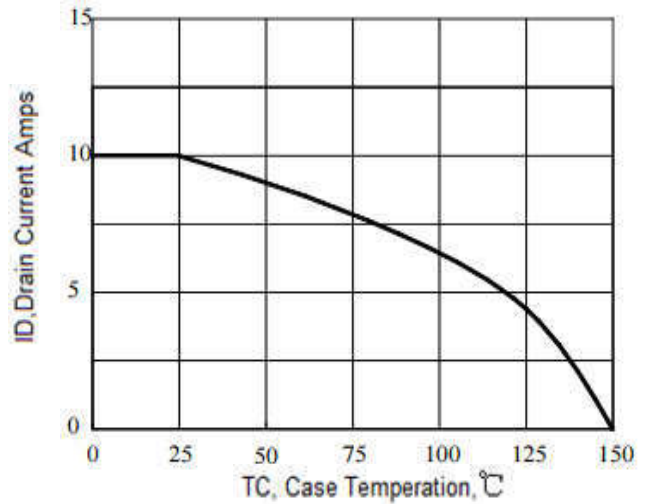
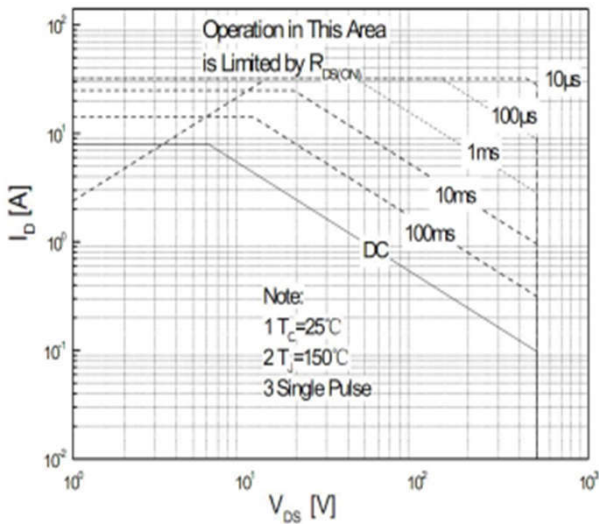
Maximum Ratings at Tc=25°C unless otherwise specified

Characteristics	Test Condition	Symbols	Min	Typ	Max	Units
Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = 250 μA	BV_{DSS}	500	-	-	V
Drain-Source Leakage Current	V _{DS} = 500 V, V _{GS} = 0 V	I_{DSS}	-	-	1	uA
	V _{DS} = 400 V, T _c = 125°C		-	-	10	
Gate Leakage Current	V _{GS} = ± 30 V, V _{DS} = 0 V	I_{GSS}	-	-	±100	nA
Gate-Source Threshold Voltage	V _{DS} = V _{GS} , I _D = 250 μA	V_{GS(th)}	2	-	4	V
Drain-Source On-State Resistance	V _{GS} = 10 V, I _D = 5 A	R_{DS(on)}	-	0.45	0.66	Ω
Forward Transconductance(Note3)	V _{DS} = 40 V, I _D = 5 A	g_{fs}	-	10	-	S
Input Capacitance	V _{GS} = 0 V, V _{DS} = 25 V, f = 1MHz	C_{iss}	-	1620	-	pF
Output Capacitance		C_{oss}	-	156	-	
Reverse Transfer Capacitance		C_{rss}	-	7	-	
Turn-on Delay Time	I _D = 10 A, V _{DD} = 250 V, R _G = 25Ω(Note3,4)	td(ON)	-	25	-	nS
Rise Time		tr	-	20	-	
Turn-Off Delay Time		td(OFF)	-	50	-	
Fall Time		tf	-	20	-	
Total Gate Charge	I _D = 10 A, V _{DD} = 400V, V _{GS} = 10 V(Note3,4)	Q_G	-	32	-	nC
Gate to Source Charge		Q_{GS}	-	8	-	
Gate to Drain Charge		Q_{GD}	-	12	-	

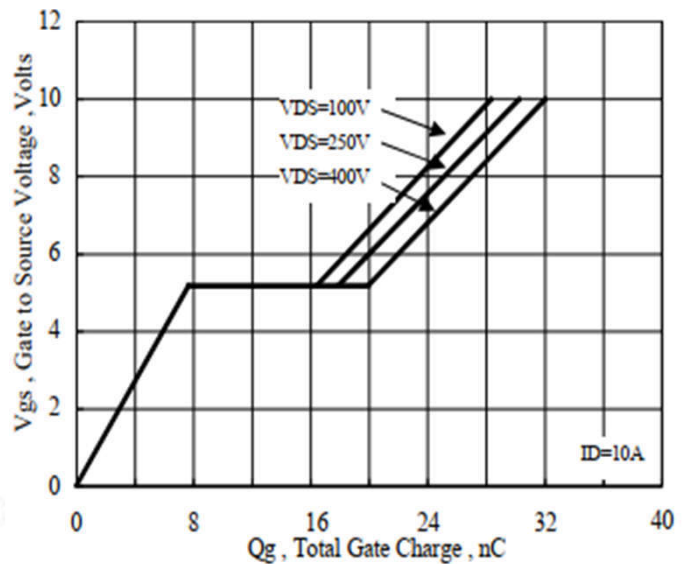
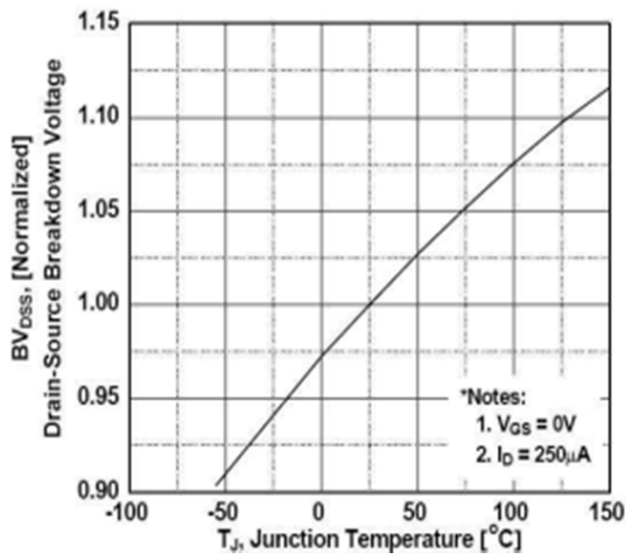
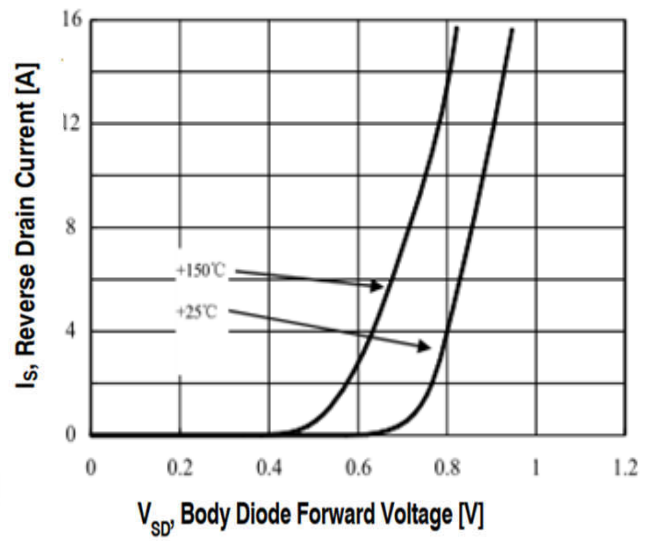
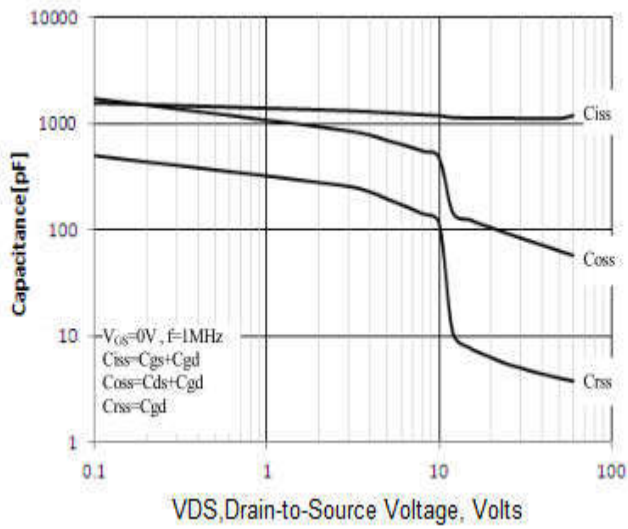
Source-Drain Diode Characteristics at Ta=25°C unless otherwise specified

Characteristics	Test Condition	Symbols	Min	Typ	Max	Units
Maximum Continuous Drain-Source Diode Forward Current		I_S	-	-	10	A
Maximum Pulsed Drain-Source Diode Forward Current		I_{SM}	-	-	40	A
Drain-Source Diode Forward Voltage	I _{SD} = 10 A	V_{SD}	-	-	1.4	V
Reverse Recovery Time	I _{SD} = 10 A, V _{GS} = 0 V, dI _F / dt = 100 A/μs (Note3)	trr	-	398	-	nS
Reverse Recovery Charge		Qrr	-	2.5	-	uC

Ratings and Characteristic Curves



Ratings and Characteristic Curves



Package Outline Dimensions millimeters

TO-220C

Dim.	Min.	Max.
A	9.8	10.2
A2	4.8	5.2
C	4.35	4.65
C1	1.45	1.05
D	0.65	0.95
E	3.45	3.75
F	2.85	3.15
G	6.4	6.8
H	0.35	0.65
J	28.68	28.98
K	2.8	3.2
M	1.15	1.45
N	Typical 2.54	
P	2.2	2.6
Q	9	9.4
S	0.15	0.35
U	2.65	2.95
DIA	宽1.50±0.10	
	深0.50 MAX	
All Dimensions in millimeter		

TO-220F

Dim.	Min.	Max.
A	9.95	10.25
B	2.95	3.25
C	1.25	1.45
D	12.95	13.25
E	0.50	0.65
F	3.1	3.3
G	1.30	1.45
H	Typ 2.54	
I	Typ 5.08	
J	4.60	4.75
K	2.50	2.65
L	6.35	6.55
M	15.4	16.0
N	2.75	3.05
O	0.48	0.52
P	0.76	0.84
All Dimensions in millimeter		

Package Outline Dimensions millimeters

TO-263

	Dim.	Min.	Max.
	A	10.1	10.2
	B	7.4	7.6
	C	1.3	1.5
	D	0.55	0.75
	E	5.0	6.0
	F	1.4	1.6
	G	0.78	0.86
	H	1.2	1.3
	I	Typ2.54	
	J	8.4	8.6
	K	4.45	4.55
	L	1.25	1.35
	M	0.02	0.1
	N	2.4	2.8
O	0.36	0.40	
All Dimensions in millimeter			